

# SANYO Semiconductors DATA SHEET

# MCH6123 — PNP Epitaxial Planar Silicon Transistor High-Current Switching Applications

### **Applications**

• DC-DC converter, relay drivers, lamp drivers, motor drivers.

#### **Features**

- · Adoption of MBIT process.
- High current capacitance.
- · Low collector-to-emitter saturation voltage.
- · High speed switching.
- Ultrasmall-sized package permitting applied sets to be made small and slim (0.85mm).
- · High allowable power dissipation.

# **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-50	V
Collector-to-Emitter Voltage	VCES		-50	V
Collector-to-Emitter Voltage	VCEO		-50	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		-6	V
Collector Current	IC		-3	А
Collector Current (Pulse)	ICP		-6	А
Base Current	IB		-600	mA
Collector Dissipation	PC	When mounted on ceramic substrate (600mm <sup>2</sup> ×0.8mm)	1	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Marking: AZ

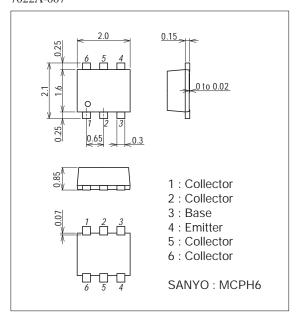
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#### Electrical Characteristics at Ta=25°C

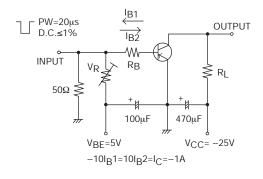
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V <sub>CB</sub> = -40V, I <sub>E</sub> =0A			-1	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> = -4V, I <sub>C</sub> =0A			-1	μΑ
DC Current Gain	hFE	V <sub>CE</sub> = -2V, I <sub>C</sub> = -100mA	200		560	
Gain-Bandwidth Product	fT	V <sub>CE</sub> = -10V, I <sub>C</sub> = -500mA		390		MHz
Output Capacitance	Cob	V <sub>CB</sub> = -10V, f=1MHz		24		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)1	I <sub>C</sub> = -1A, I <sub>B</sub> = -50mA		-115	-230	mV
	V <sub>CE</sub> (sat)2	I <sub>C</sub> = -2A, I <sub>B</sub> = -100mA		-240	-650	mV
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> = -2A, I <sub>B</sub> = -100mA		-0.88	-1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC= -10μA, IE=0A	-50			V
Collector-to-Emitter Breakdown Voltage	V(BR)CES	I <sub>C</sub> = -100μA, R <sub>BE</sub> =0Ω	-50			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> = -1mA, R <sub>BE</sub> =∞	-50			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> = -10μA, I <sub>C</sub> =0A	-6			V
Turn-On Time	ton	See specified Test Circuit.		30		ns
Storage Time	tstg	See specified Test Circuit.		230		ns
Fall Time	tf	See specified Test Circuit.		18		ns

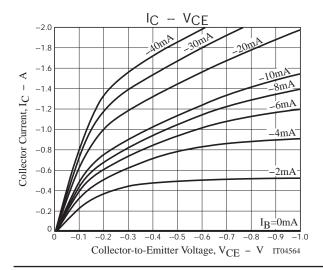
### **Package Dimensions**

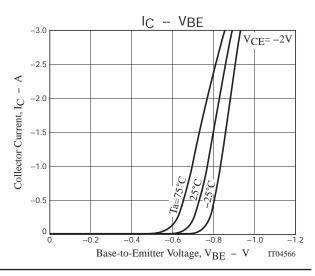
unit : mm (typ) 7022A-007

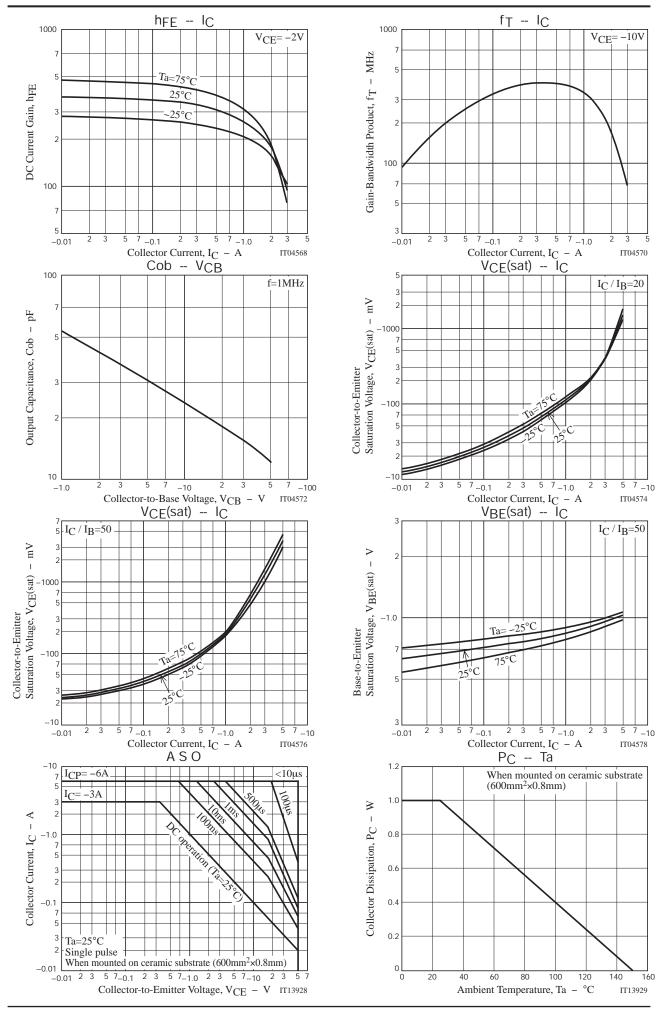


# **Switching Time Test Circuit**









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